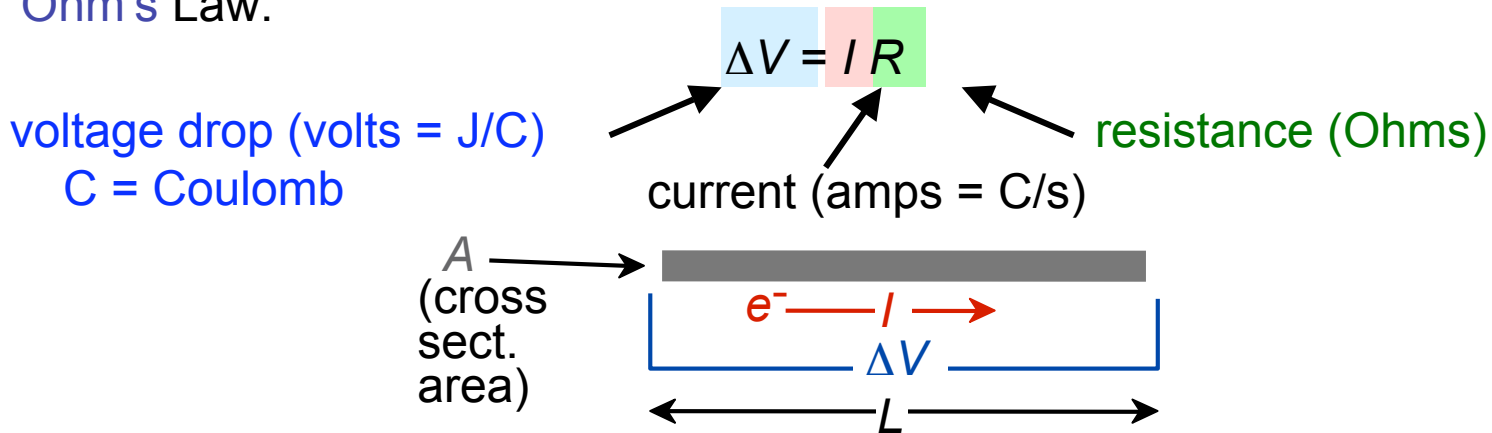


Electrical conductivity

- Ohm's Law:



- Resistivity, ρ and Conductivity, σ :
 - geometry-independent forms of Ohm's Law
 - Resistivity is a material property & is independent of sample

Conductivity: comparison

- Room T values $(\text{Ohm-m})^{-1} = (\Omega - \text{m})^{-1}$

METALS

conductors

Silver

6.8×10^7

Copper

6.0×10^7

Iron

1.0×10^7

CERAMICS

Soda-lime glass

10^{-10} - 10^{-11}

Concrete

10^{-9}

Aluminum oxide

$<10^{-13}$

SEMICONDUCTORS

Silicon

4×10^{-4}

Germanium

2×10^0

GaAs

10^{-6}

semiconductors

POLYMERS

Polystyrene

$<10^{-14}$

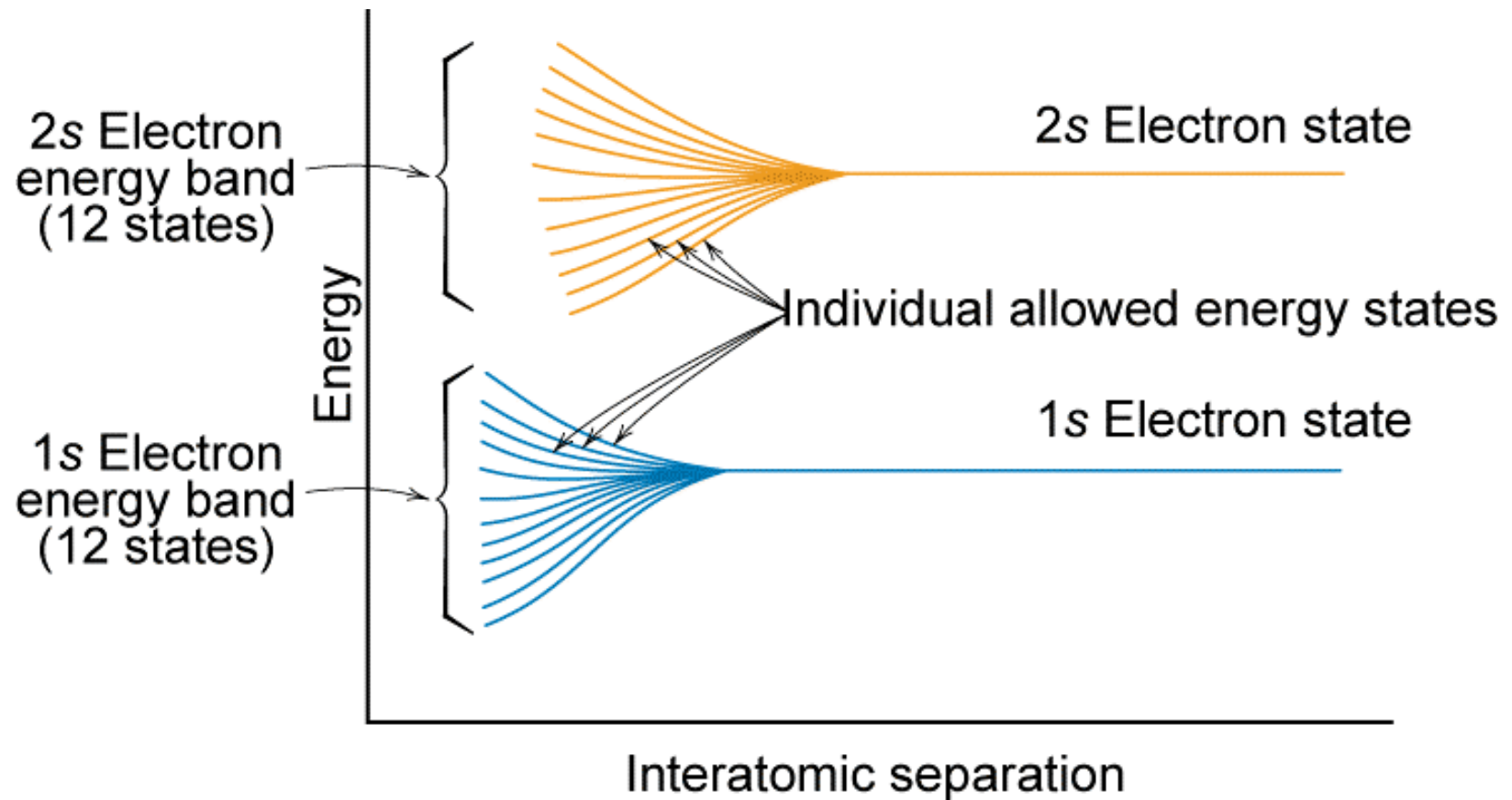
Polyethylene

10^{-15} - 10^{-17}

insulators

Selected values from Tables 18.1, 18.3, and 18.4, *Callister 7e*.

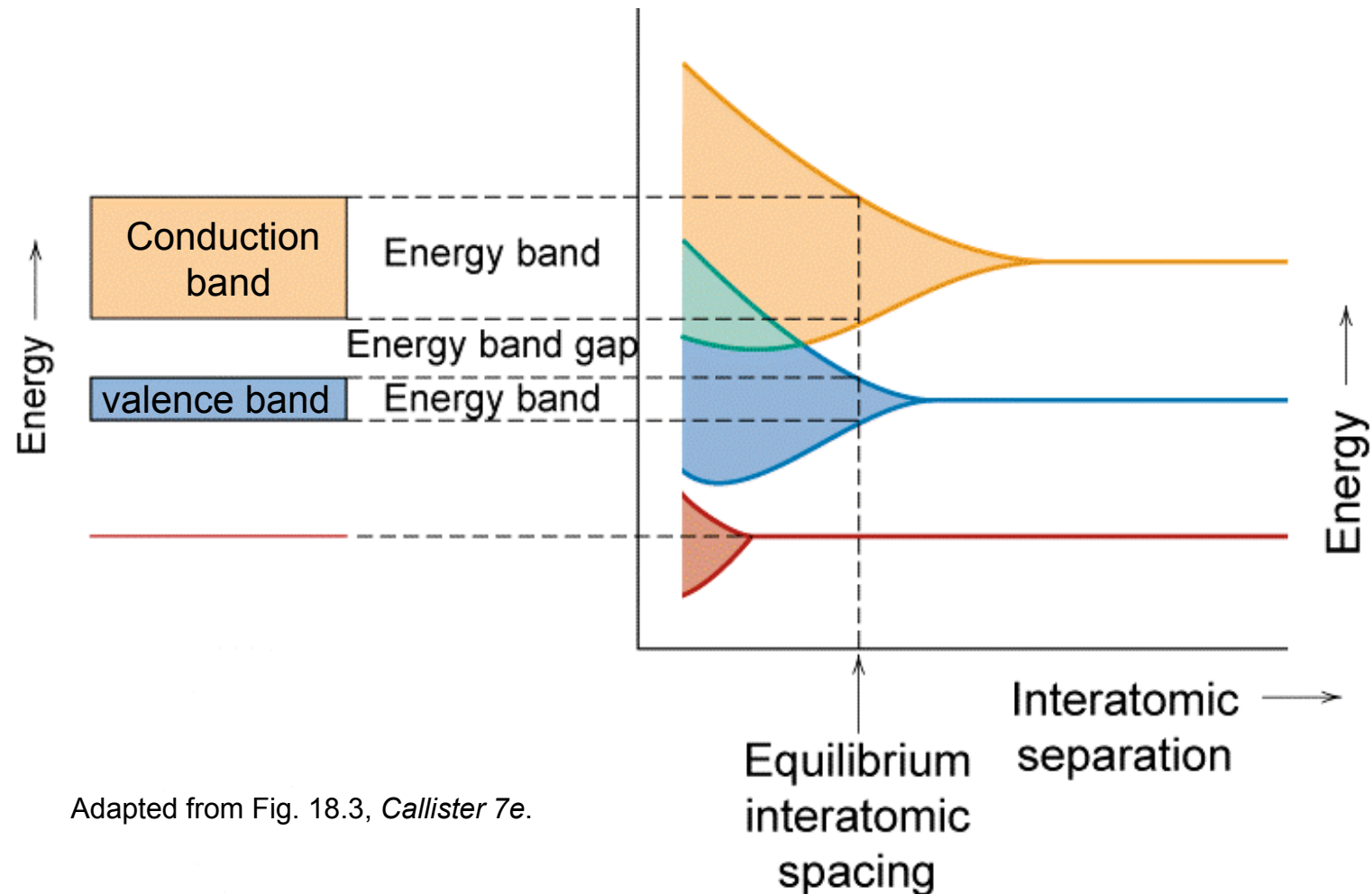
Electronic band structure



Adapted from Fig. 18.2, *Callister 7e*.

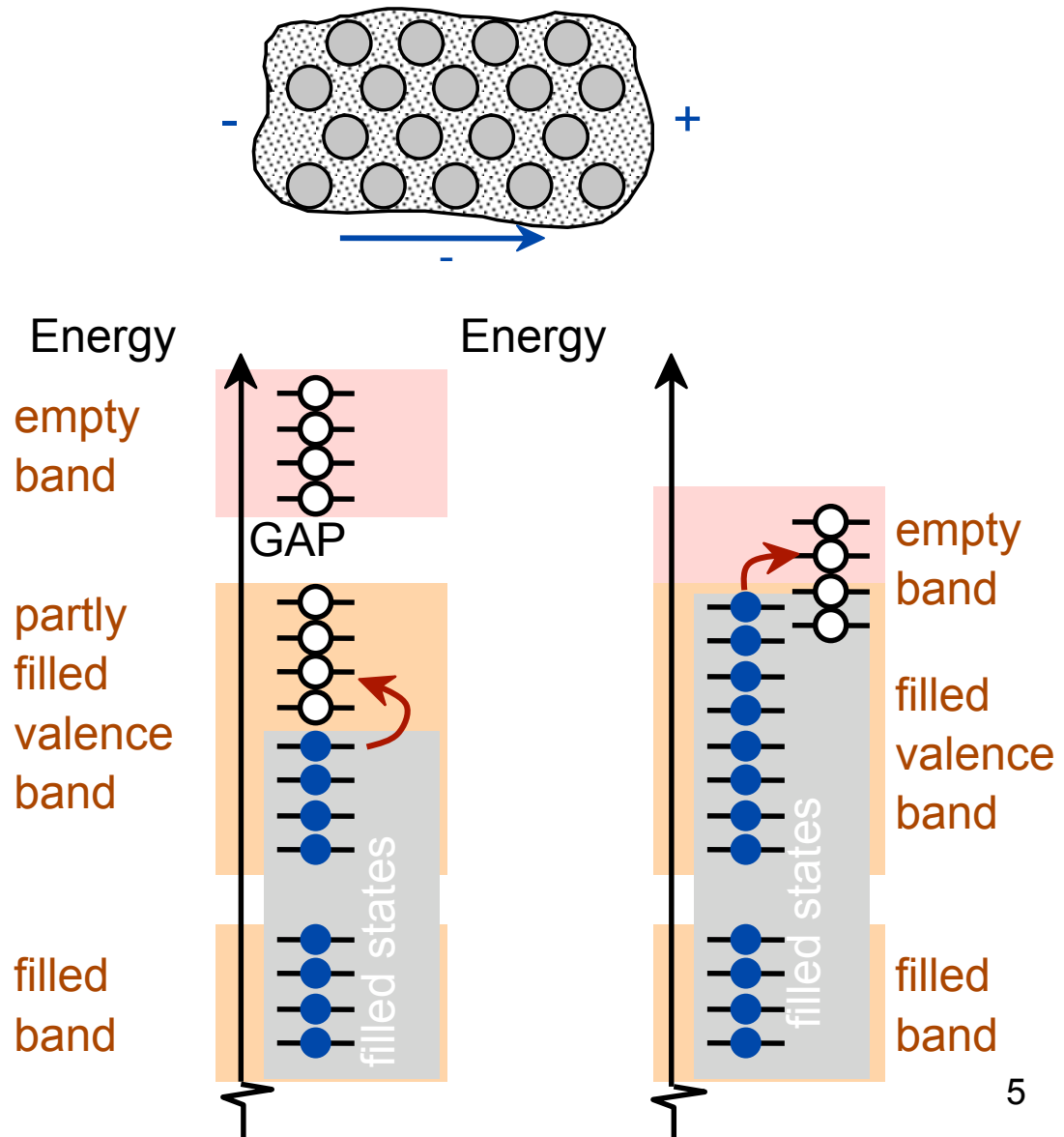
Electronic band structure

- Valence band – filled – highest occupied energy levels
- Conduction band – empty – lowest unoccupied energy levels

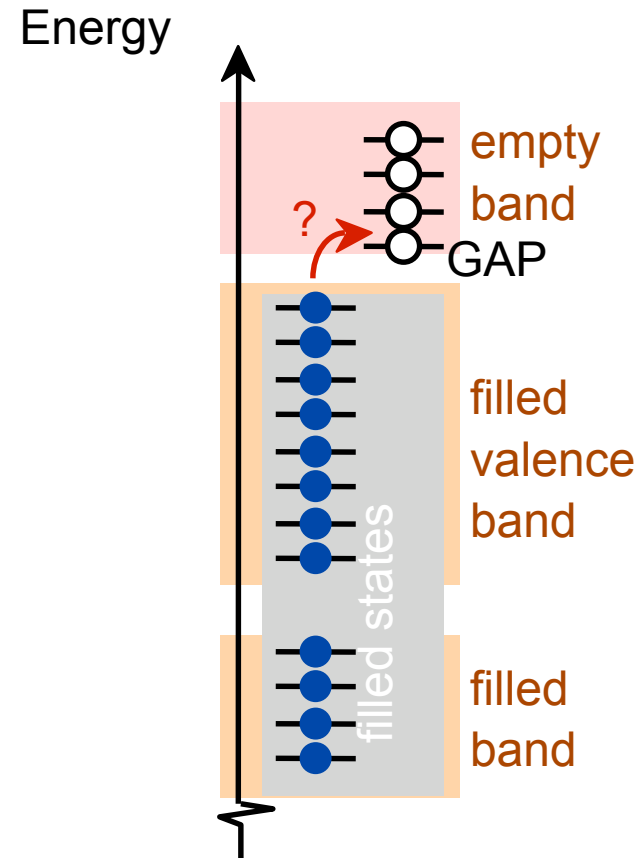
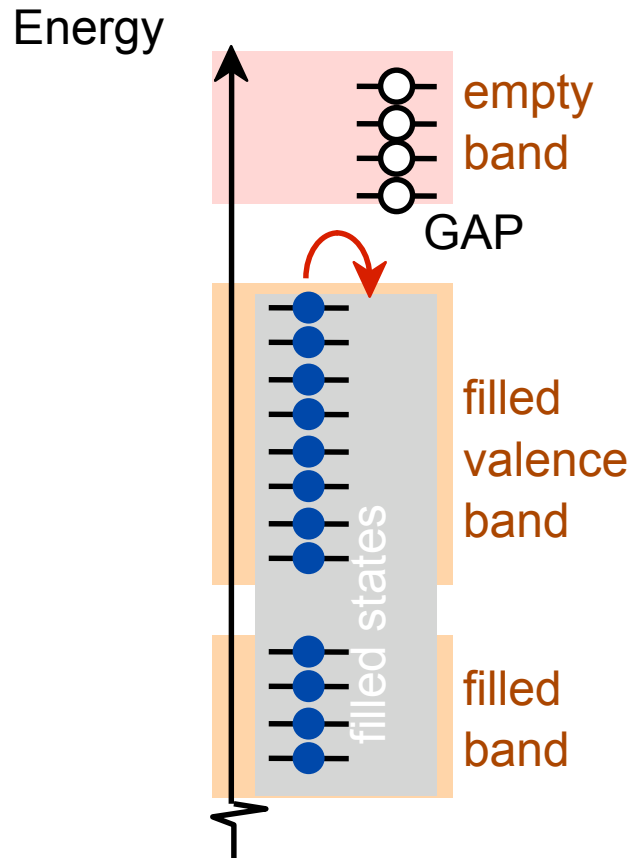


Adapted from Fig. 18.3, *Callister 7e*.

Conduction and electron transport

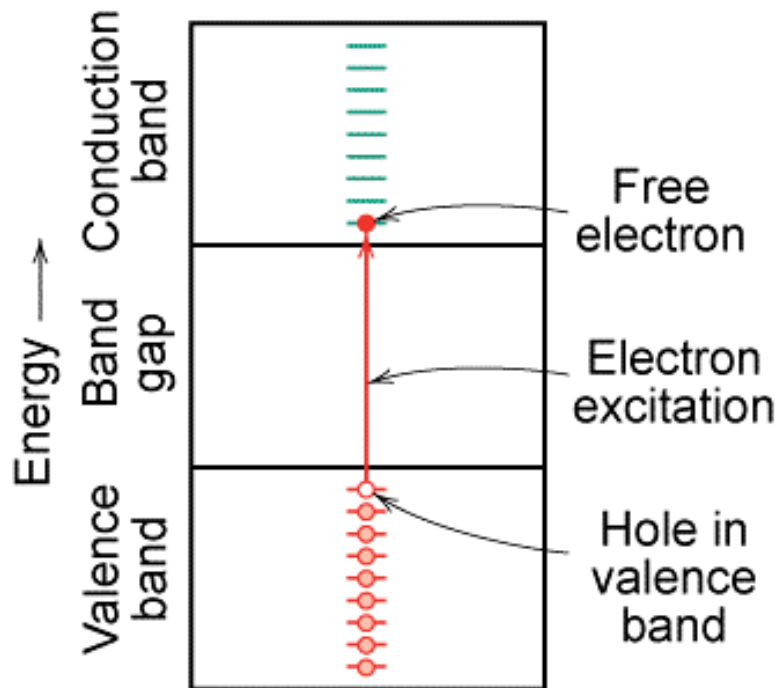


Energy states: Insulators & semiconductors



Charge carriers

Adapted from Fig. 18.6 (b), *Callister 7e*.



Two charge carrying mechanisms

Electron – negative charge

Hole – equal & opposite positive charge

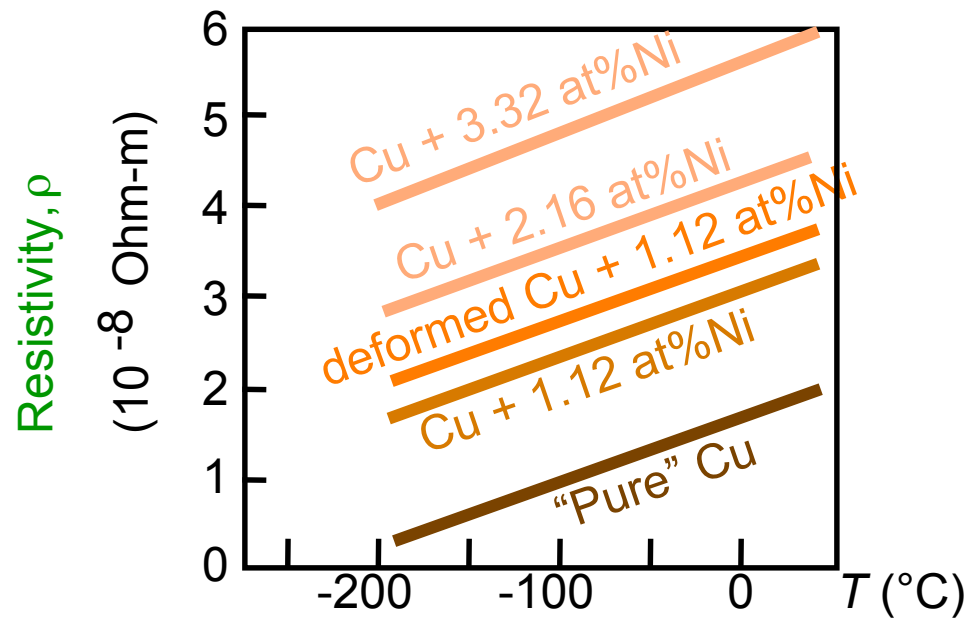
Move at different speeds - **drift velocity**

Higher temp. promotes more electrons into the conduction band

$\therefore \sigma \uparrow$ as $T \uparrow$

Electrons scattered by impurities, grain boundaries, etc.

Charge carriers

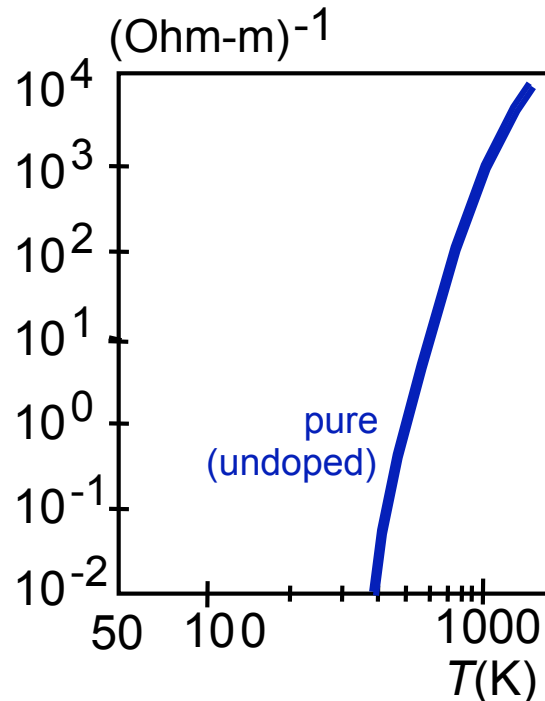


Adapted from Fig. 18.8, *Callister 7e*. (Fig. 18.8 adapted from J.O. Linde, *Ann. Physik* **5**, p. 219 (1932); and C.A. Wert and R.M. Thomson, *Physics of Solids*, 2nd ed., McGraw-Hill Book Company, New York, 1970.)

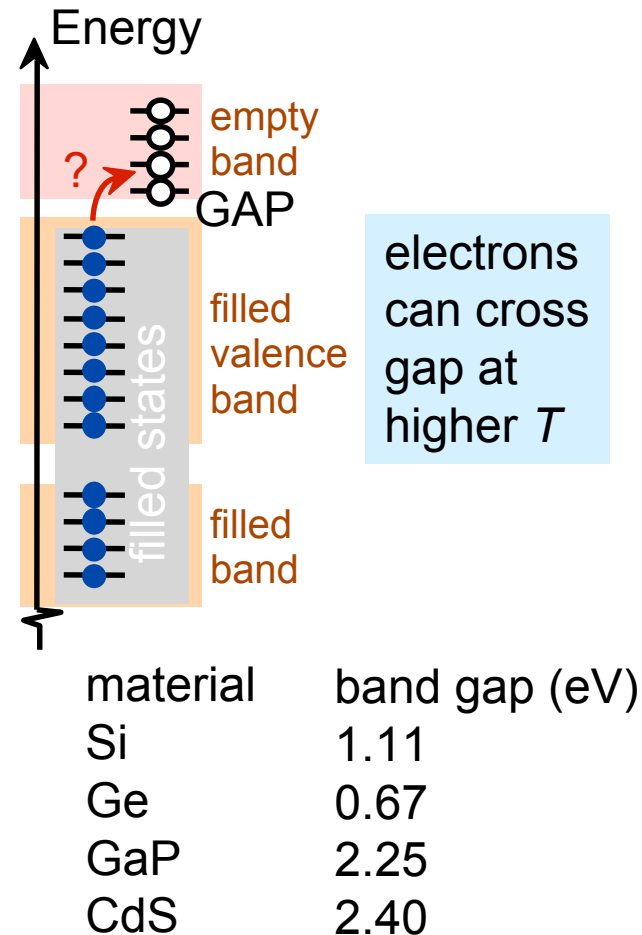
Pure semiconductors: Conductivity vs T

- Data for **Pure Silicon**:
 - σ increases with T
 - opposite to metals

electrical conductivity, σ



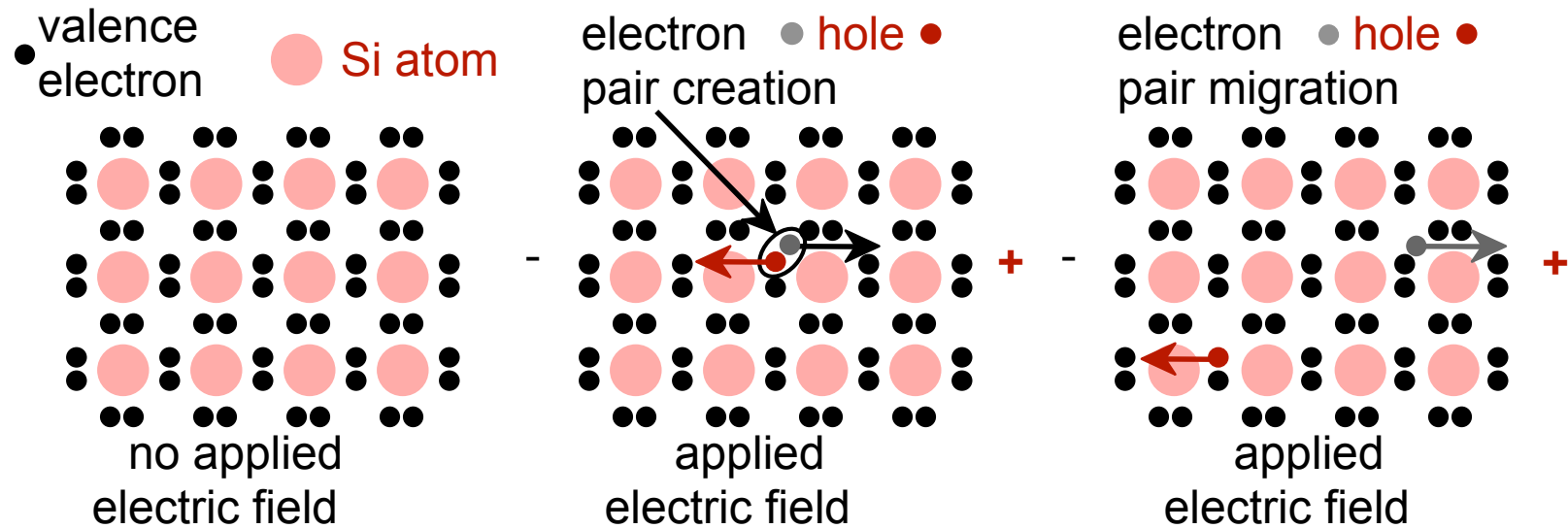
Adapted from Fig. 19.15, *Callister 5e*. (Fig. 19.15 adapted from G.L. Pearson and J. Bardeen, *Phys. Rev.* **75**, p. 865, 1949.)



Selected values from Table 18.3, *Callister 7e*.

Conduction in terms of electron and hole migration

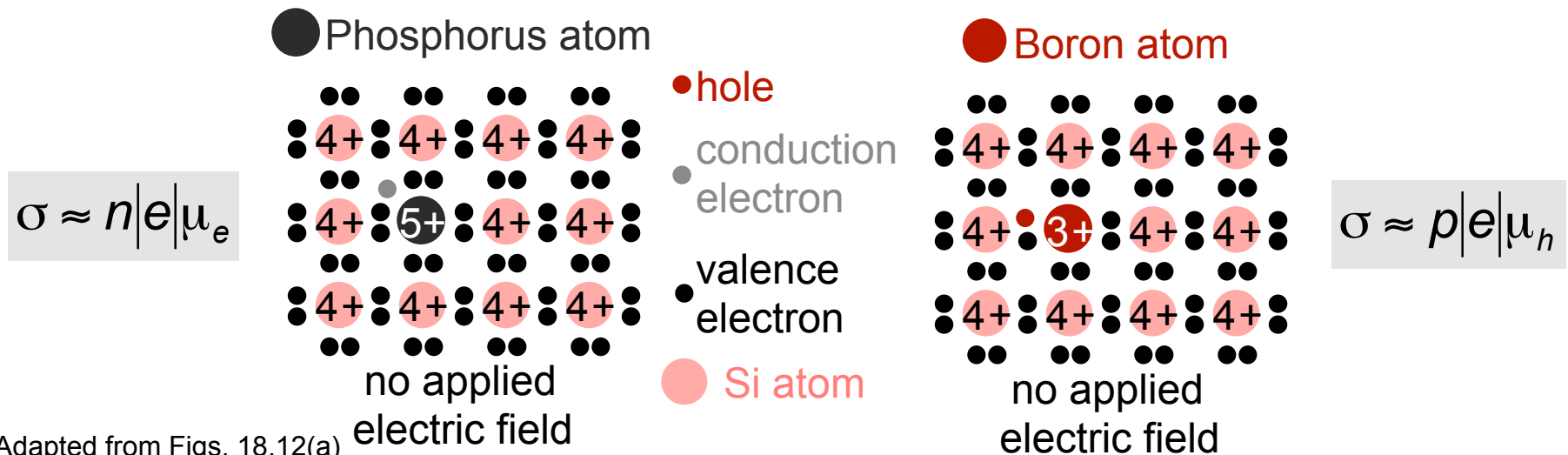
- Concept of electrons and holes:



Adapted from Fig. 18.11,
Callister 7e.

Intrinsic vs extrinsic conduction

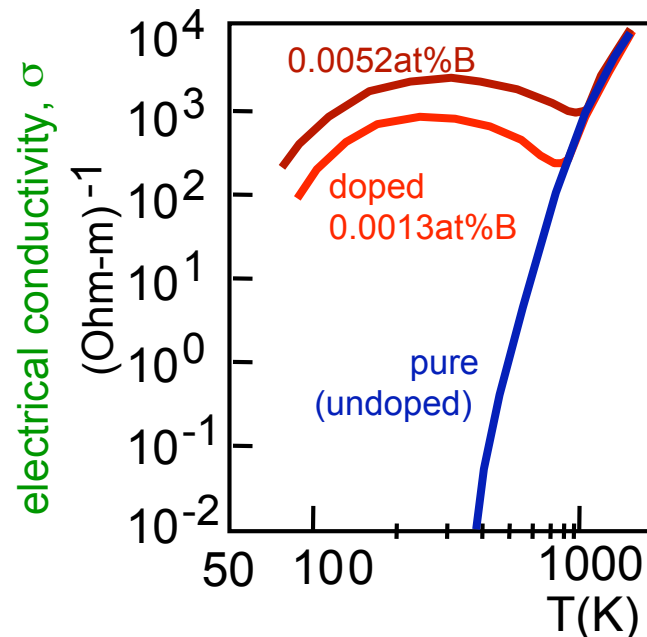
- **Intrinsic:**
electrons = # holes ($n = p$)
--case for pure Si
- **Extrinsic:**
-- $n \neq p$
--occurs when impurities are added with a different # valence electrons than the host (e.g., Si atoms)
- **n -type Extrinsic:** ($n \gg p$)
- **p -type Extrinsic:** ($p \gg n$)



Adapted from Figs. 18.12(a)
& 18.14(a), *Callister 7e*.

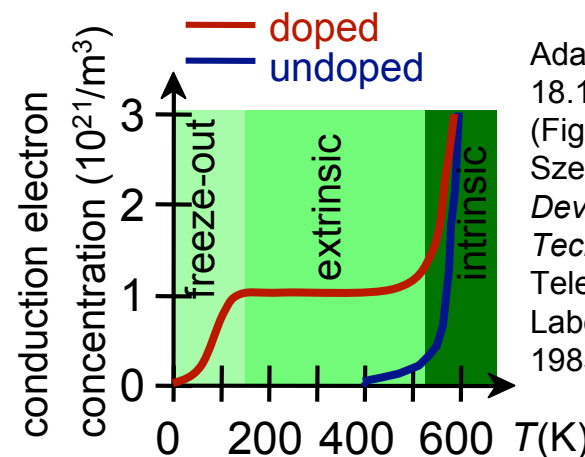
Doped semiconductor: conductivity vs. T

- Data for Doped Silicon:
 - σ increases with doping
 - reason: imperfection sites lower the activation energy to produce mobile electrons.



Adapted from Fig. 19.15, *Callister 5e*. (Fig. 19.15 adapted from G.L. Pearson and J. Bardeen, *Phys. Rev.* **75**, p. 865, 1949.)

- Comparison: **intrinsic** vs extrinsic conduction...
 - extrinsic doping level: $10^{21}/\text{m}^3$ of a *n*-type donor impurity (such as P).
 - for $T < 100$ K: "freeze-out", thermal energy insufficient to excite electrons.
 - for $150 \text{ K} < T < 450 \text{ K}$: "extrinsic"
 - for $T \gg 450 \text{ K}$: "intrinsic"



Adapted from Fig. 18.17, *Callister 7e*. (Fig. 18.17 from S.M. Sze, *Semiconductor Devices, Physics, and Technology*, Bell Telephone Laboratories, Inc., 1985.)

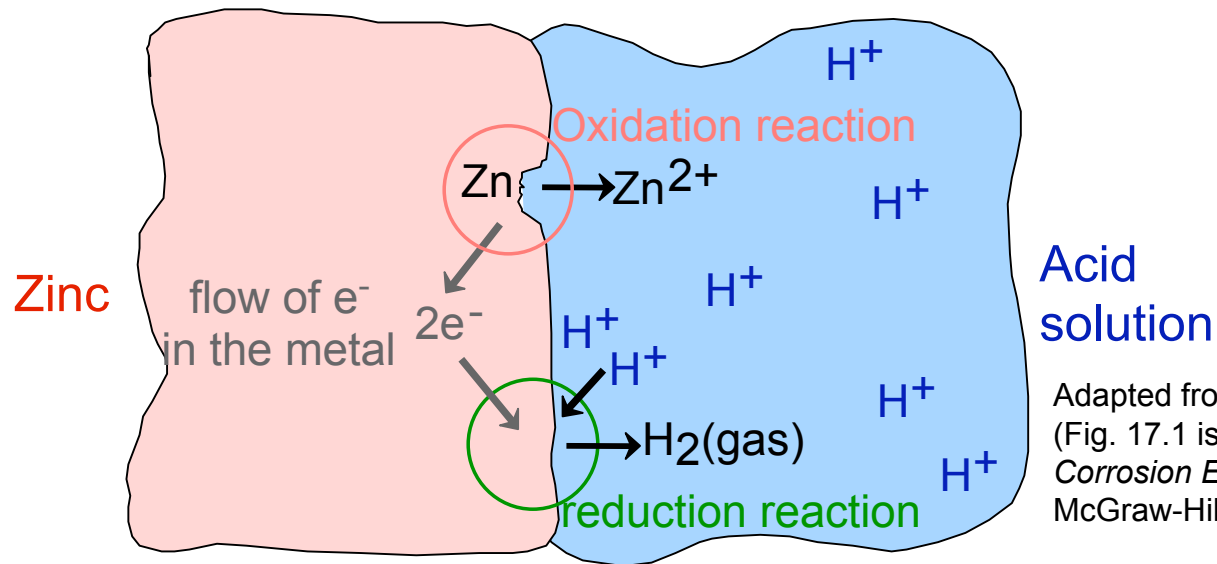
Doped semiconductor: conductivity vs. T

Intrinsic Conductivity

$$\sigma = n|e|\mu_e + p|e|\mu_e$$

Corrosion of zinc in acid

- Two reactions are necessary:
 - oxidation reaction:
 - **reduction** reaction:

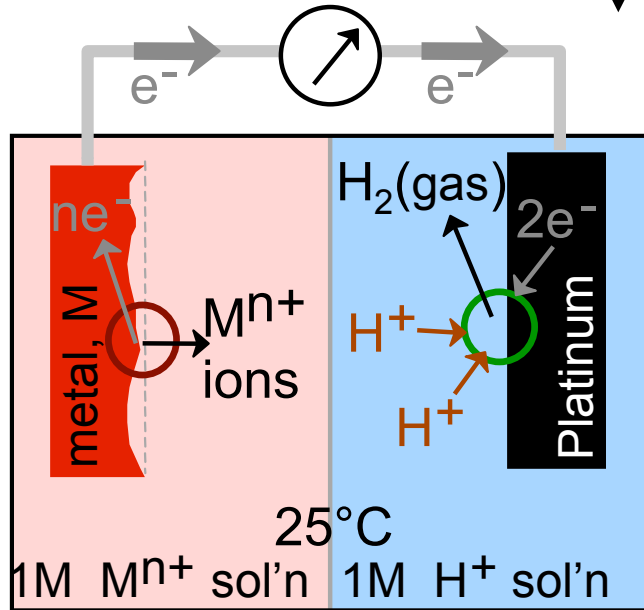


Adapted from Fig. 17.1, *Callister 7e*.
(Fig. 17.1 is from M.G. Fontana,
Corrosion Engineering, 3rd ed.,
McGraw-Hill Book Company, 1986.)

Standard hydrogen (EMF) test

- Two outcomes:

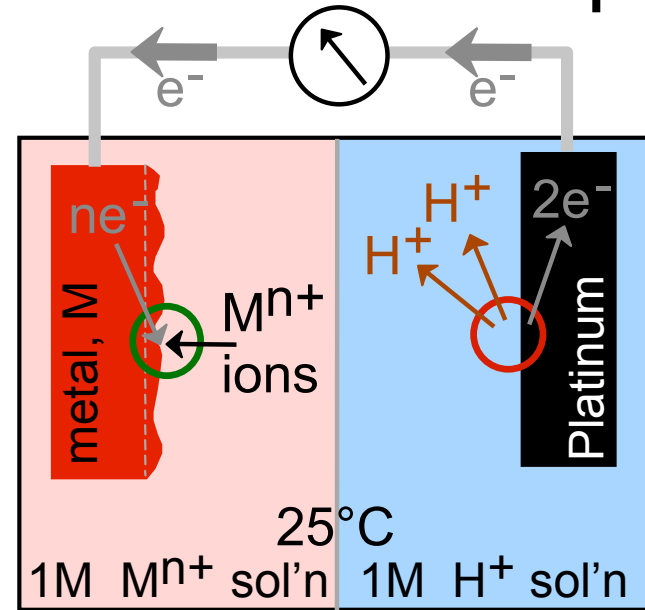
--Metal sample mass ↓



--Metal is the anode (-)

$$V_{\text{metal}}^0 < 0 \quad (\text{relative to Pt})$$

--Metal sample mass ↑



--Metal is the cathode (+)

$$V_{\text{metal}}^0 > 0 \quad (\text{relative to Pt})$$

Standard Electrode Potential

Adapted from Fig. 17.2, Callister 7e.

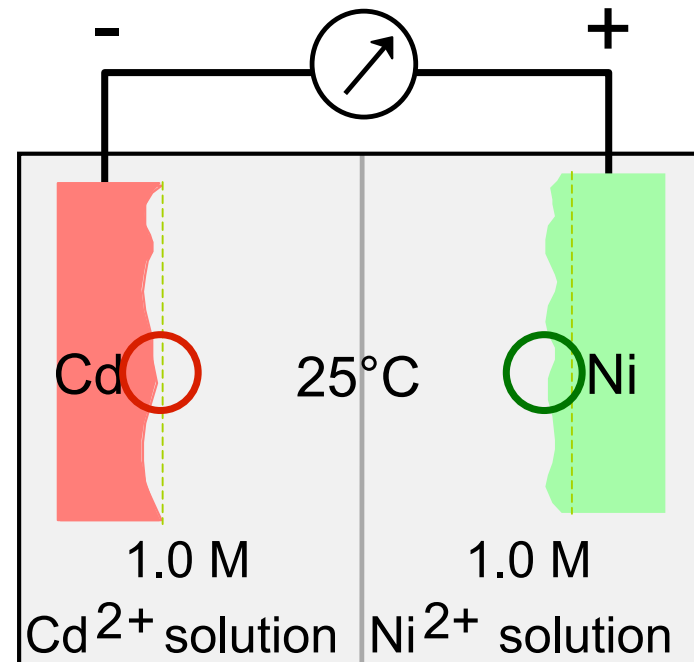
Standard EMF series

- EMF series

	metal	V_{metal}°	
↑ more cathodic	Au	+1.420 V	
	Cu	+0.340	
	Pb	- 0.126	
	Sn	- 0.136	
	Ni	- 0.250	↕ $\Delta V^{\circ} = 0.153\text{V}$ ↕
Co	- 0.277		
Cd	- 0.403		
↓ more anodic	Fe	- 0.440	
	Cr	- 0.744	
	Zn	- 0.763	
	Al	- 1.662	
	Mg	- 2.363	
	Na	- 2.714	
	K	- 2.924	

Data based on ⁺
Callister 7e.

- Metal with smaller V_{metal}^0 corrodes.
- Ex: Cd-Ni cell



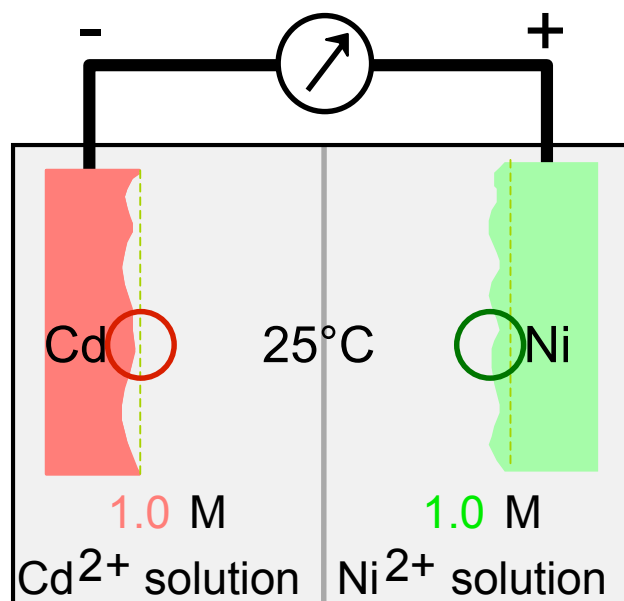
Data based on Table 17.1,
Callister 7e.

Adapted from Fig. 17.2, Callister 7e.

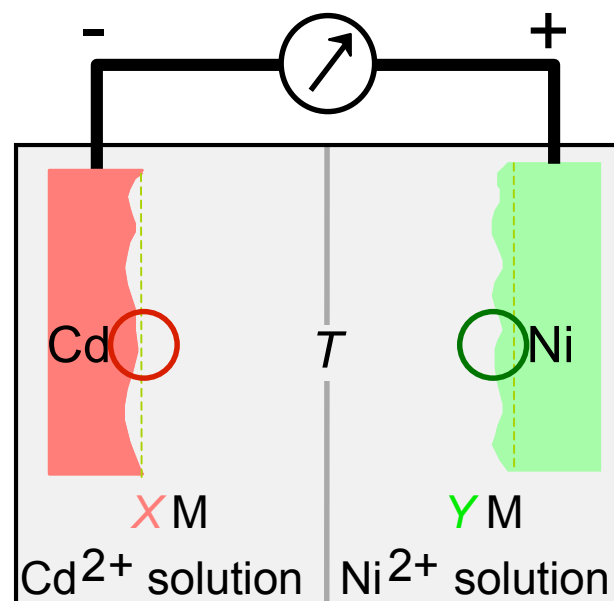
Effect of solution concentration

- Ex: Cd-Ni cell with standard 1 M solutions

$$V_{\text{Ni}}^{\circ} - V_{\text{Cd}}^{\circ} = 0.153$$



- Ex: Cd-Ni cell with non-standard solutions



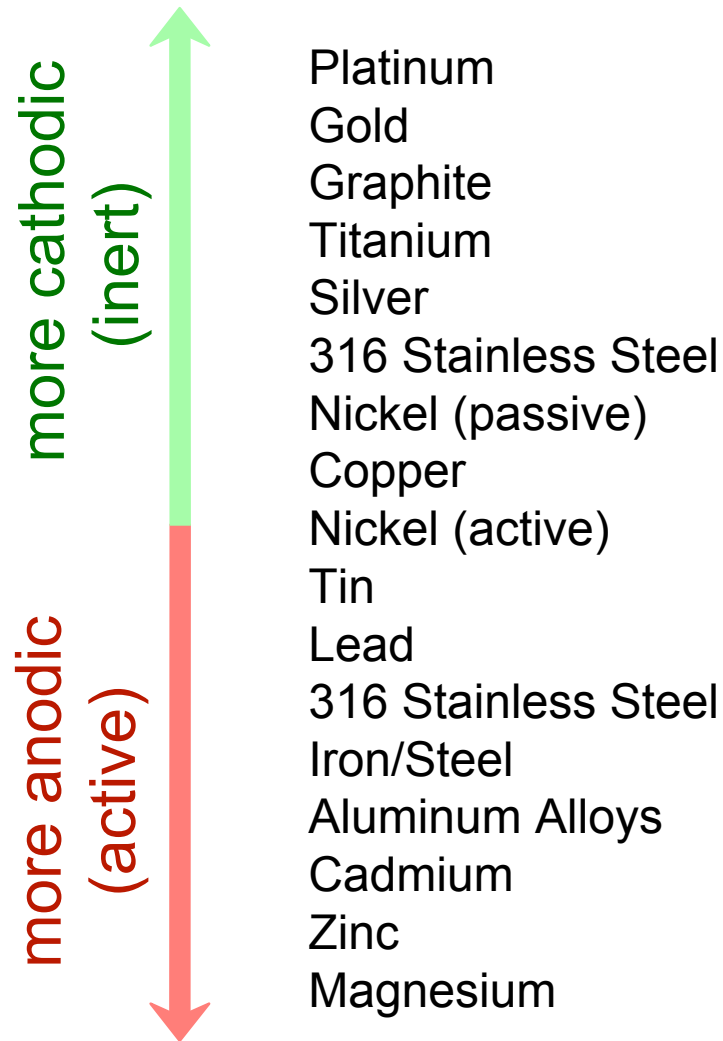
$n = \#e^-$
per unit
oxid/red
reaction
(= 2 here)

$F =$
Faraday's
constant
= 96,500
C/mol.

- Reduce $V_{\text{Ni}} - V_{\text{Cd}}$ by
--increasing X
--decreasing Y

Galvanic series

- Ranks the reactivity of metals/alloys in seawater



Based on Table 17.2, *Callister 7e*. (Source of Table 17.2 is M.G. Fontana, *Corrosion Engineering*, 3rd ed., McGraw-Hill Book Company, 1986.)

Forms of corrosion

- **Uniform Attack**

Oxidation & reduction occur uniformly over surface.

- **Selective Leaching**

Preferred corrosion of one element/constituent (e.g., Zn from brass (Cu-Zn)).

- **Intergranular**

Corrosion along grain boundaries, often where special phases exist.

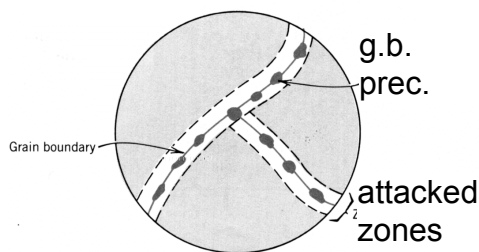


Fig. 17.18, Callister 7e.

- **Stress corrosion**

Stress & corrosion work together at crack tips.

- **Erosion-corrosion**

Break down of passivating layer by erosion (pipe elbows).

- **Pitting**

Downward propagation of small pits & holes.

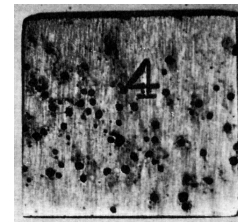


Fig. 17.17, Callister 7e. (Fig. 17.17 from M.G. Fontana, *Corrosion Engineering*, 3rd ed., McGraw-Hill Book Company, 1986.)

- **Galvanic**

Dissimilar metals are physically joined. The more anodic one corrodes. (see Table 17.2) Zn & Mg very anodic.

- **Crevice** Between two pieces of the same metal.

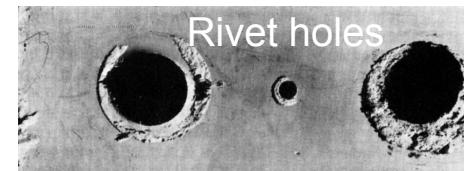
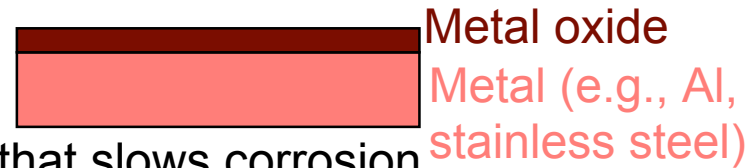


Fig. 17.15, Callister 7e. (Fig. 17.15 is courtesy LaQue Center for Corrosion Technology, Inc.)

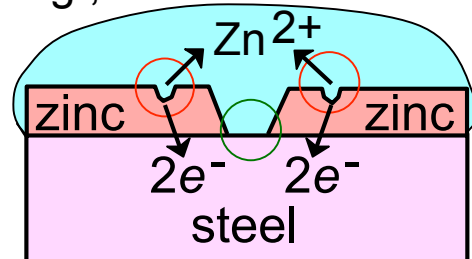
Controlling corrosion

- Self-protecting metals!
 - Metal ions combine with O to form a thin, adhering oxide layer that slows corrosion.



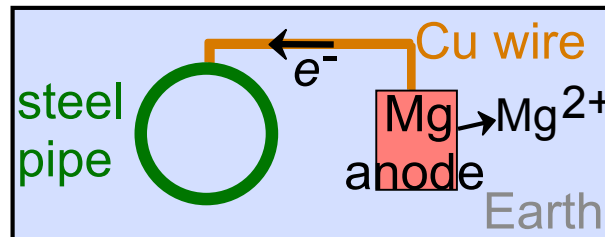
- Reduce T (slows kinetics of oxidation and reduction)
- Add inhibitors
 - Slow oxidation/reduction reactions by removing reactants (e.g., remove O_2 gas by reacting it w/an inhibitor).
 - Slow oxidation reaction by attaching species to the surface (e.g., paint it!).
- Cathodic (or sacrificial) protection
 - Attach a more anodic material to the one to be protected.

e.g., zinc-coated nail



Adapted from Fig. 17.23, Callister 7e.

e.g., Mg Anode



Adapted from Fig. 17.22(a), Callister 7e. (Fig. 17.22(a) is from M.G. Fontana, *Corrosion Engineering*, 3rd ed., McGraw-Hill Book Co., 1986.)